	i e	
167.116	GaAs P++	
166_115	Al _{x1} Ga _{1-x1} As p	_
165114	Al _{x2} Ga _{1-x2} As P+	
164 113	Al _{x2} Ga _{1-x2} As und	
163 112	Al _{x2} Ga _{1-x2} As N+	
162 111=	Al _{x2} Ga _{1-x2} As und	
161 110	GaAs und	-
159-108-	In _{y1} Ga _{1-yi} YAs und	
160109	GaAs und	$\frac{1}{2}$ x 1 - 3
158 107	GaAs und	_
157,106	Al _{x2} Ga _{1-x2} As und	<u></u>
156 —	Alxi Gaz-xi As und	
171.105	Al _{x1} Ga _{1-x1} As p	
170104	GaAs p+	_)
151,103	AlAs und	
152102	GaAs und	
151101	AlAs und	<u>. 1819</u>
100	GaAs SI Substrate	_ FIG.1



